# NSN 5961-00-304-8346

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### **Inclosure Material:**

Metal

## **Overall Length:**

Between 1.553 inches and 1.573 inches

## **Overall Height:**

0.380 inches

# **Overall Width:**

1.050 inches

## **Mounting Facility Quantity:**

2

## Internal Configuration:

Junction contact

# Joint Electronic Device Engineering Council/jedec/case Outline Designation:

### To-204aa

Electrode Internally-electrically Connected To Case:

Collector

### Mounting Method:

Unthreaded hole

## Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

150.0 collector to base voltage/static/emitter open and 120.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage, static, collector open

### **Current Rating Per Characteristic:**

Between 10.00 amperes source cutoff current and 30.00 amperes source cutoff current

# Power Rating Per Characteristic:

140.0 watts small-signal input power, common-collector preset

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

### **Special Features:**

Junction pattern arrangement: npn

### Test Data Document:

81413-231250 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

# **Terminal Type And Quantity:**

2 pin and 1 case

Shelf Life:

N/a

Unit Of Measure:

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# Demilitarization:

No

Fiig:

A110a0